

Engineering/Process Change Notice

ECN/PCN No.: 4465

For Manufacturer					
Product Description: Ceramic SMD Crystal Oscillator	Abracon Part Numb EH46 Series	er / Part Series:	 □ Documentation ⊠ ECN ⊠ EOL 	only ⊠ Series □ Part Number	
Affected Revision: Rev. D 06/08/2012	New Revision:	DL	Application:	□ Safety ⊠ Non-Safety	
Prior to Change: ACTIVE	1		I		
After Change: EOL					
Cause/Reason for Change: Discontinuation of manufacturing capabilit	ty				
	Chan	ge Plan			
Effective Date: 11/15/2022	Additional Remarks: N/A				
Change Declaration: N/A					
Issued Date: 11/15/22	Issued By: Conor Healey		Issued Department: Engineering		
Approval:	Approval:		Approval:		
Thomas Culhane	Reuben Q	uintanilla	Ying Huang		
Engineering Director	Quality	Director	Purchasing Director		
	For Abrac	on EOL only			
Last Time Buy (if applicable): None	Alternate Part Number / Part Series: ASEDV, ASE, AP3S		S		
Additional Approval:	Additional Approval: Additional Approval:		al:		
Customer Approval (If Applicable)					
Qualification Status: Note: It is considered approved if there is n		Not accepted ustomer 1 month afte	r ECN/PCN is release	ed.	
Customer Part Number:					
Company Name:	Company Representative:		Representative Sig	;nature:	
Customer Remarks:					

Form #7020 | Rev. G | Effective: 02/22/2021 |

Page **1** of **1**



Ecliptek









EH46 Series



REGULATORY COMPLIANCE

Lead Free	EU RoHS	China RoHS	REACH
\bigotimes	2011/65 + 2015/863	e	SVHC
COMPLIANT	COMPLIANT	COMPLIANT	COMPLIANT



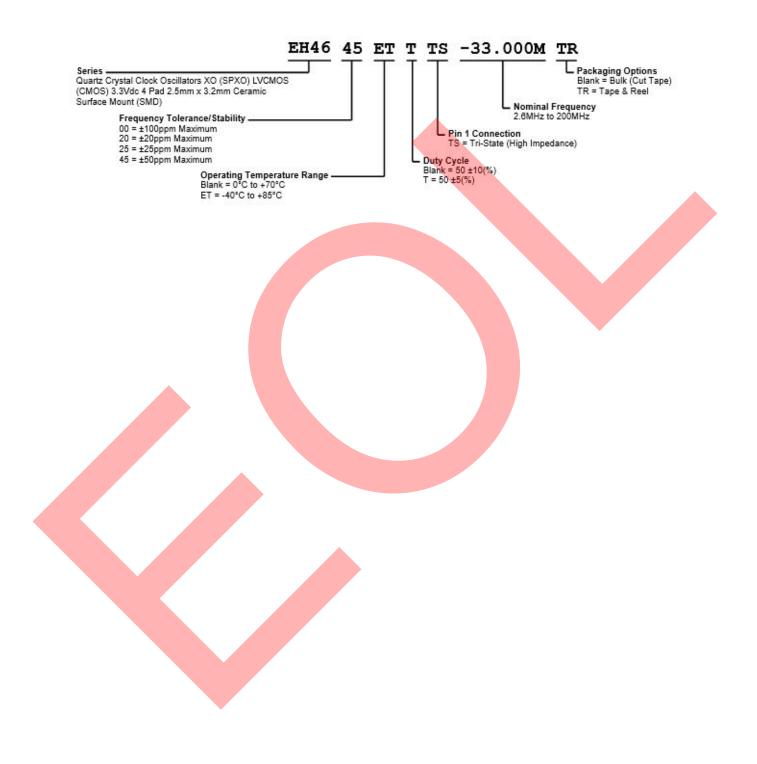
ITEM DESCRIPTION

Quartz Crystal Clock Oscillators XO (SPXO) LVCMOS (CMOS) 3.3Vdc 4 Pad 2.5mm x 3.2mm Ceramic Surface Mount (SMD)

ELECTRICAL SPECIFICAT	
Nominal Frequency	2.6MHz to 200MHz
Frequency Tolerance/Stability	Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°, 260°C Reflow, Shock, and Vibration ±100ppm Maximum ±20ppm Maximum ±25ppm Maximum ±50ppm Maximum
Aging at 25°C	±5ppm/year Maximum
Operating Temperature Range	0°C to +70°C -40°C to +85°C
Supply Voltage	3.3Vdc ±5%
Input Current	No Load 10mA Maximum over Nominal Frequency of 2.6MHz to 25MHz 12mA Maximum over Nominal Frequency of 25.000001MHz to 50MHz 13mA Maximum over Nominal Frequency of 50.000001MHz to 166MHz 16mA Maximum over Nominal Frequency of 166.000001MHz to 200MHz
Output Voltage Logic High (Voh)	IOH = -8mA 90% of Vdd Minimum
Output Voltage Logic Low (V _{ol})	IOL = +8mA 10% of Vdd Maximum
Rise/Fall Time	Measured at 20% to 80% of waveform 6nSec Maximum over Nominal Frequency of 2.6MHz to 50MHz 4nSec Maximum over Nominal Frequency of 50.000001MHz to 75MHz 2nSec Maximum over Nominal Frequency of 75.000001MHz to 200MHz
Duty Cycle	Measured at 50% of waveform 50 ±10(%) 50 ±5(%)
Load Drive Capability	30pF Maximum over Nominal Frequency of 2.6MHz to 50MHz 15pF Maximum over Nominal Frequency of 50.000001MHz to 200MHz
Output Logic Type	CMOS
Pin 1 Connection	Tri-State (High Impedance)
Tri-State Input Volta <mark>ge (Vih and Vil)</mark>	90% of Vdd Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output (High Impedance).
Standby Current	10μA Maximum (Pin <mark>1 = Groun</mark> d)
RMS Phase Jitter	Fj = 12kHz to 20 <mark>MHz</mark> 20pSec Typic <mark>al, 30pSec</mark> Maximum
Period Jitter (RMS)	10pSec Typical
Period Jitter (pk-pk)	60pSec Typical, 100pSec Maximum
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

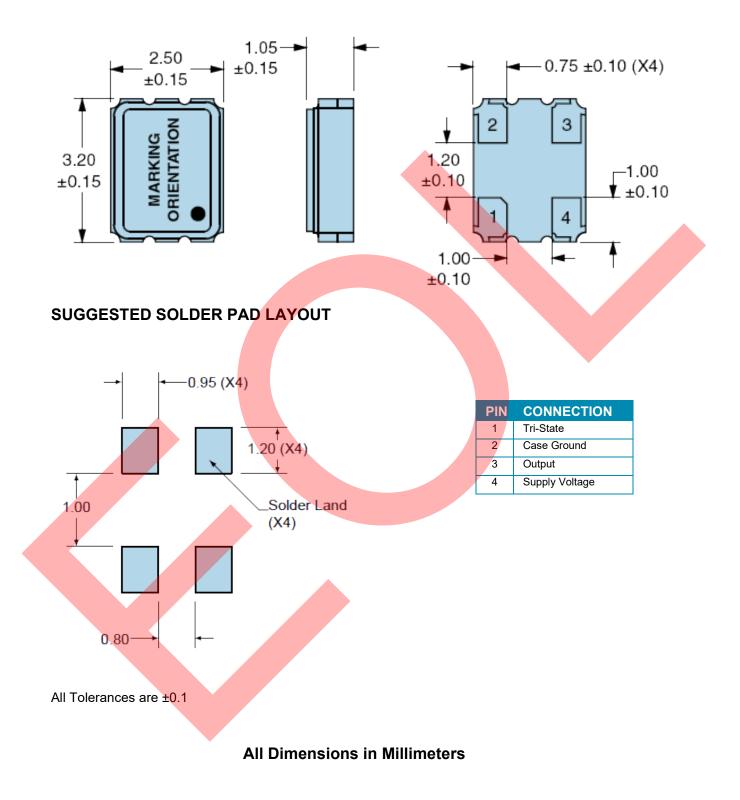


PART NUMBERING GUIDE



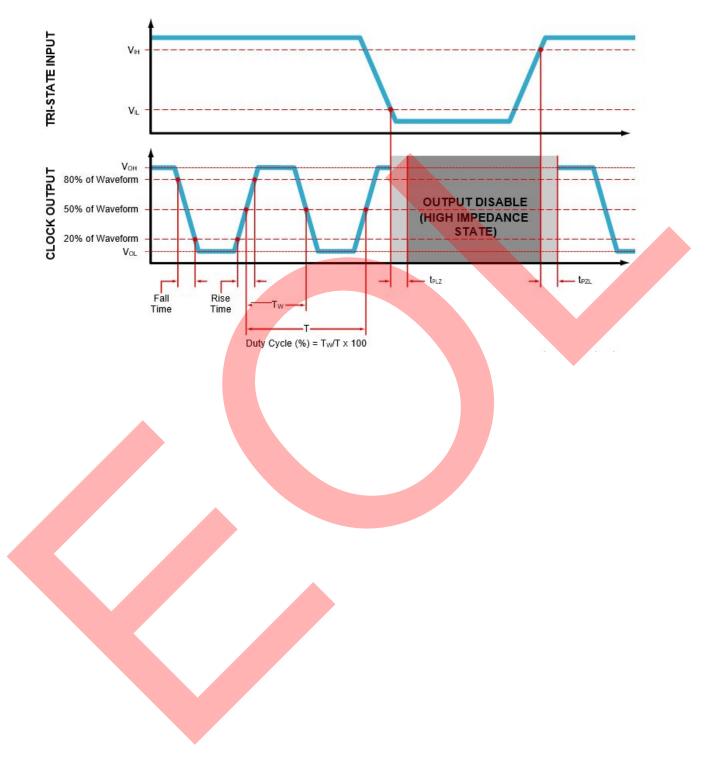


MECHANICAL DIMENSIONS



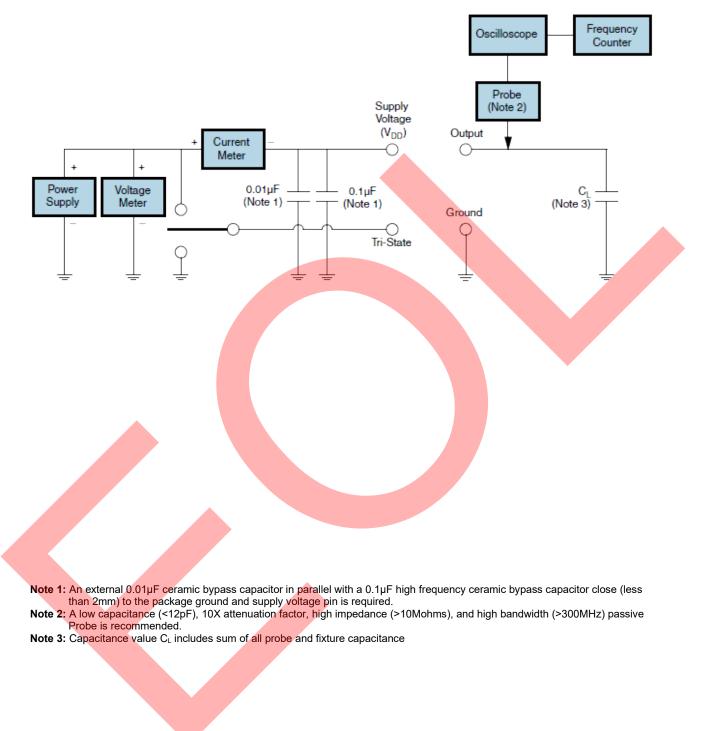


OUTPUT WAVEFORM & TIMING DIAGRAM





TEST CIRCUIT FOR CMOS OUTPUT



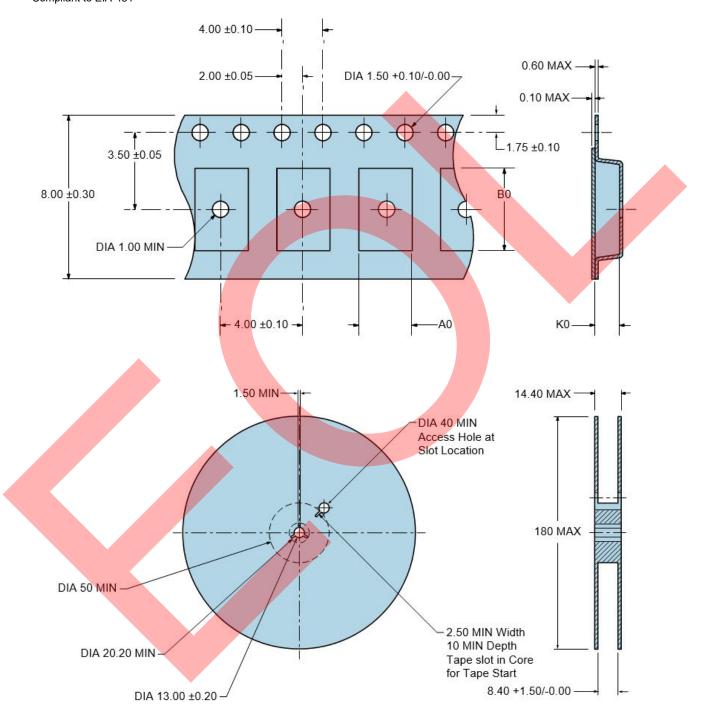
EH46 Series



TAPE & REEL DIMENSIONS

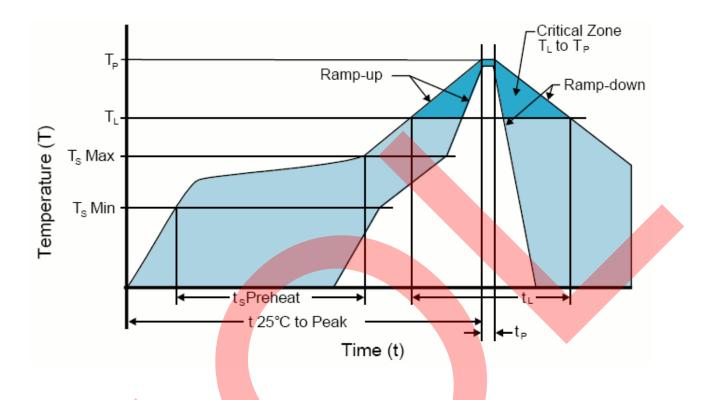
Quantity per Reel: 1,000 Units All Dimensions in Millimeters

Compliant to EIA-481





RECOMMENDED SOLDER REFLOW METHOD



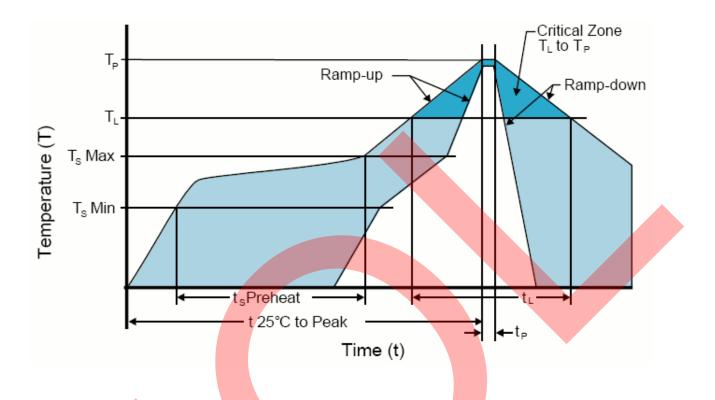
HIGH TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	3°C/Second Maximum	
Preheat		
 Temperature Minimum (T_S MIN) 	150°C	
- Temperature Typical (Ts TYP)	175°C	
	200°C	
- Time (t _s)	60 - 180 Seconds	
Ramp-up Rate (T _L to T _P)	3°C/Second Maximum	
Time Maintained Above:		
- Temperature (T _L)	217°C	
- Time (t _L)	60 - 150 Seconds	
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum	
Target Peak Temperature(TP Target)	250°C +0/-5°C	
Time within 5°C of actual peak (t _p)	20 - 4 <mark>0 Seconds</mark>	
Ramp-down Rate	6°C/Second Maximum	
Time 25°C to Peak Temperature (t)	8 Minutes Maximum	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)



RECOMMENDED SOLDER REFLOW METHOD



LOW TEMPERATURE INFRARED/CONVECTION		
T _s MAX to T _L (Ramp-up Rate)	5°C/Second Maximum	
Preheat		
 Temperature Minimum (T_s MIN) 	N/A	
- Temperature Typical (T _s TYP)	150°C	
	N/A	
- Time (t _s)	60 - 120 Seconds	
Ramp-up Rate (T _L to T _P)	5°C/Second Maximum	
Time Maintained Above:		
- Temperature (TL)	150°C	
- Time (t _L)	200Seconds Maximum	
Peak Temperature (T _P)	240°C Maximum	
Target Peak Temperature (TP Target)	240°C M <mark>aximum 2</mark> Times / 230°C Maximum 1 Time	
Time within 5°C of actual peak (t _p)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time	
Ramp-down Rate	5° <mark>C/Second</mark> Maximum	
Time 25°C to Peak Temperature (t)	N/A	
Moisture Sensitivity Level	Level 1	
Additional Notes	Temperatures shown are applied to body of device.	

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperatures shown are applied to body of device.)